



NPN SILICON TRANSISTOR
Qualified per MIL-PRF-19500/366

Qualified Levels:
 JAN, JANTX, JANTXV
 and JANS

DESCRIPTION

This family of 2N3498L thru 2N3501L epitaxial planar transistors are military qualified up to a JANS level for high-reliability applications. These devices are also available in TO-39 and low profile U4 packaging. Microsemi also offers numerous other transistor products to meet higher and lower power ratings with various switching speed requirements in both through-hole and surface-mount packages.

Important: For the latest information, visit our website <http://www.microsemi.com>.

FEATURES

- JEDEC registered 2N3498 through 2N3501 series.
- JAN, JANTX, JANTXV, and JANS qualifications are available per MIL-PRF-19500/366. (See [part nomenclature](#) for all available options.)
- RoHS compliant versions available (commercial grade only).

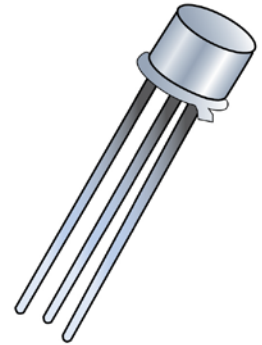
APPLICATIONS / BENEFITS

- General purpose transistors for medium power applications requiring high frequency switching.
- Low package profile.
- Military and other high-reliability applications.

MAXIMUM RATINGS

Parameters / Test Conditions	Symbol	2N3498L 2N3499L	2N3500L 2N3501L	Unit
Collector-Emitter Voltage	V_{CEO}	100	150	V
Collector-Base Voltage	V_{CBO}	100	150	V
Emitter-Base Voltage	V_{EBO}	6.0	6.0	V
Collector Current	I_C	500	300	mA
Thermal Resistance Junction-to-Ambient	$R_{\theta JA}$	175		$^{\circ}C/W$
Thermal Resistance Junction-to-Case	$R_{\theta JC}$	30		$^{\circ}C/W$
Total Power Dissipation @ $T_A = +25^{\circ}C$ ⁽¹⁾ @ $T_C = +25^{\circ}C$ ⁽²⁾	P_T	1.0 5.0		W
Operating & Storage Junction Temperature Range	T_J, T_{stg}	-65 to +200		$^{\circ}C$

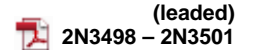
- Notes:** 1. See [figure 1](#).
 2. See [figure 2](#).



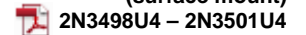
TO-5 Package

Also available in:

TO-39 (TO-205AD) package



U4 package
(surface mount)



MSC – Lawrence

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 Fax: (978) 689-0803

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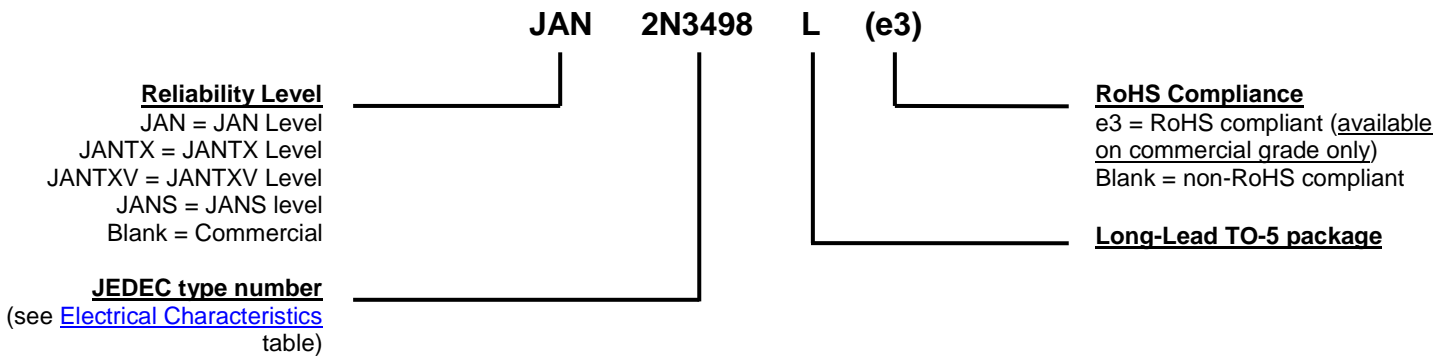
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 Ennis, Co. Clare, Ireland
 Tel: +353 (0) 65 6840044
 Fax: +353 (0) 65 6822298

Website:

www.microsemi.com

MECHANICAL and PACKAGING

- CASE: Hermetically sealed, kovar base, nickel cap.
- TERMINALS: Leads are kovar, nickel plated, and finish is solder dip (Sn63/Pb37). Can be RoHS compliant with pure matte-tin (commercial grade only).
- MARKING: Part number, date code, manufacturer's ID.
- WEIGHT: Approximately 1.14 grams.
- See [Package Dimensions](#) on last page.

PART NOMENCLATURE

SYMBOLS & DEFINITIONS

Symbol	Definition
C_{obo}	Common-base open-circuit output capacitance
I_{CEO}	Collector cutoff current, base open
I_{CEX}	Collector cutoff current, circuit between base and emitter
I_{EBO}	Emitter cutoff current, collector open
h_{FE}	Common-emitter static forward current transfer ratio
V_{CEO}	Collector-emitter voltage, base open
V_{CBO}	Collector-emitter voltage, emitter open
V_{EBO}	Emitter-base voltage, collector open

ELECTRICAL CHARACTERISTICS @ $T_A = +25\text{ }^\circ\text{C}$, unless otherwise noted

Characteristic	Symbol	Min.	Max.	Unit
OFF CHARACTERISTICS				
Collector-Emitter Breakdown Voltage $I_C = 10\text{ mA}$, pulsed	$V_{(BR)CEO}$	100		V
2N3498L, 2N3499L 2N3500L, 2N3501L		150		
Collector-Base Cutoff Current $V_{CB} = 50\text{ V}$	I_{CBO}		50	nA
$V_{CB} = 75\text{ V}$			50	nA
$V_{CB} = 100\text{ V}$			10	μA
$V_{CB} = 150\text{ V}$			10	μA
Emitter-Base Cutoff Current $V_{EB} = 4.0\text{ V}$	I_{EBO}		25	nA
$V_{EB} = 6.0\text{ V}$			10	μA

ON CHARACTERISTICS ⁽¹⁾

Forward-Current Transfer Ratio $I_C = 0.1\text{ mA}$, $V_{CE} = 10\text{ V}$	h_{FE}	2N3498L, 2N3500L	20		
		2N3499L, 2N3501L	35		
$I_C = 1.0\text{ mA}$, $V_{CE} = 10\text{ V}$		2N3498L, 2N3500L	25		
		2N3499L, 2N3501L	50		
$I_C = 10\text{ mA}$, $V_{CE} = 10\text{ V}$		2N3498L, 2N3500L	35		
		2N3499L, 2N3501L	75		
$I_C = 150\text{ mA}$, $V_{CE} = 10\text{ V}$		2N3498L, 2N3500L	40	120	
	2N3499L, 2N3501L	100	300		
$I_C = 300\text{ mA}$, $V_{CE} = 10\text{ V}$	2N3500L	15			
	2N3501L	20			
$I_C = 500\text{ mA}$, $V_{CE} = 10\text{ V}$	2N3498L	15			
	2N3499L	20			
Collector-Emitter Saturation Voltage $I_C = 10\text{ mA}$, $I_B = 1.0\text{ mA}$	$V_{CE(sat)}$	All Types		0.2	V
$I_C = 300\text{ mA}$, $I_B = 30\text{ mA}$		2N3498L, 2N3499L		0.6	
$I_C = 150\text{ mA}$, $I_B = 15\text{ mA}$		2N3500L, 2N3501L		0.4	
Base-Emitter Saturation Voltage $I_C = 10\text{ mA}$, $I_B = 1.0\text{ mA}$	$V_{BE(sat)}$	All Types		0.8	V
$I_C = 300\text{ mA}$, $I_B = 30\text{ mA}$		2N3498L, 2N3499L		1.4	
$I_C = 150\text{ mA}$, $I_B = 15\text{ mA}$		2N3500L, 2N3501L		1.2	

DYNAMIC CHARACTERISTICS

Forward Current Transfer Ratio, Magnitude $I_C = 20\text{ mA}$, $V_{CE} = 20\text{ V}$, $f = 100\text{ MHz}$	$ h_{fe} $	1.5	8.0	
Output Capacitance $V_{CB} = 10\text{ V}$, $I_E = 0$, $100\text{ kHz} \leq f \leq 1.0\text{ MHz}$	C_{obo}	2N3498L, 2N3499L	10	pF
		2N3500L, 2N3501L	8.0	
Input Capacitance $V_{EB} = 0.5\text{ V}$, $I_C = 0$, $100\text{ kHz} \leq f \leq 1.0\text{ MHz}$	C_{ibo}		80	pF

(1) Pulse Test: pulse width = 300 μs , duty cycle $\leq 2.0\%$.

ELECTRICAL CHARACTERISTICS ($T_A = +25\text{ }^\circ\text{C}$, unless otherwise noted)

SWITCHING CHARACTERISTICS

Characteristic	Symbol	Min.	Max.	Unit
Turn-On Time $V_{EB} = 5\text{ V}; I_C = 150\text{ mA}; I_{B1} = 15\text{ mA}$	t_{on}		115	ns
Turn-Off Time $I_C = 150\text{ mA}; I_{B1} = I_{B2} = -15\text{ mA}$	t_{off}		1150	ns

SAFE OPERATING AREA (See SOA figure and reference [MIL-STD-750 method 3053](#))

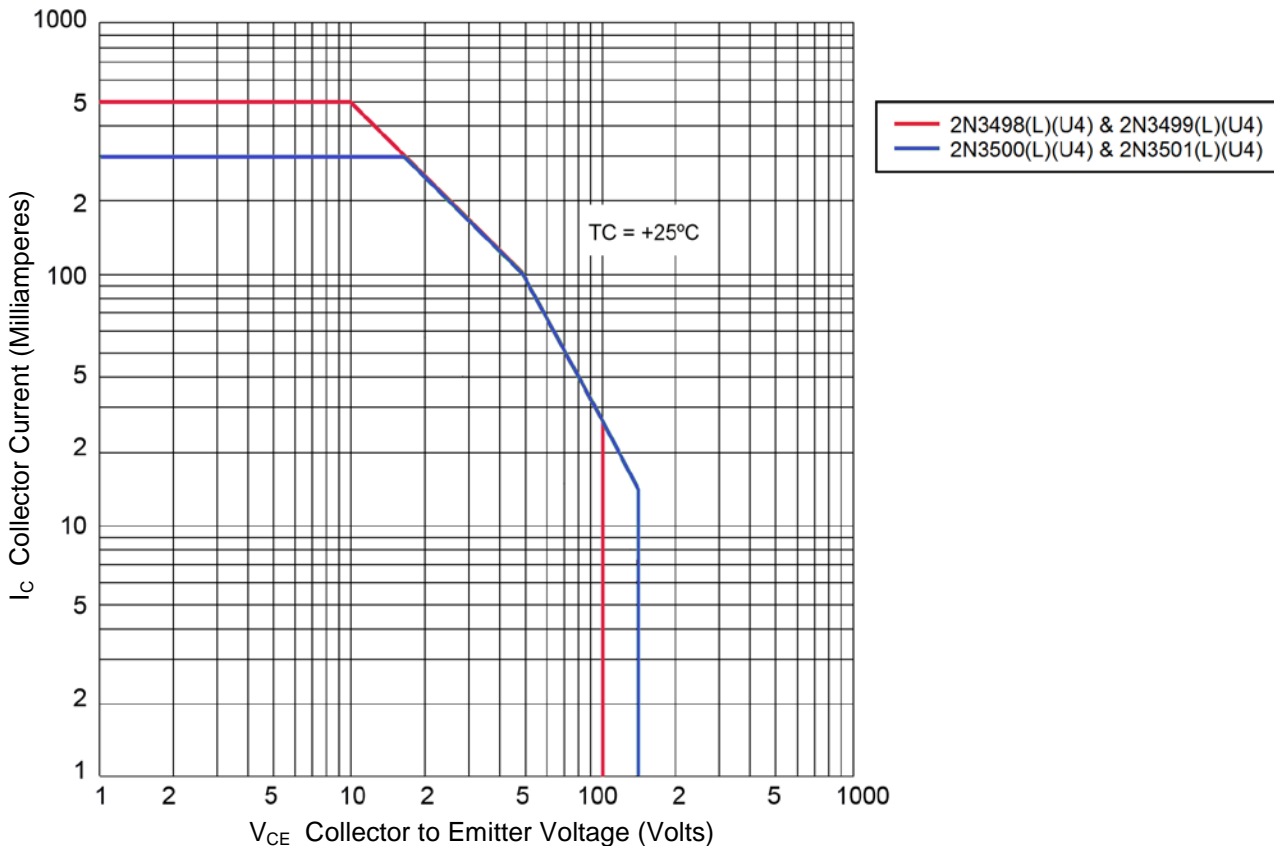
DC Tests
 $T_C = +25\text{ }^\circ\text{C}$, $t_r \geq 10\text{ ns}$; 1 Cycle, $t = 1.0\text{ s}$
Test 1
 $V_{CE} = 10\text{ V}, I_C = 500\text{ mA}$ 2N3498L, 2N3499L

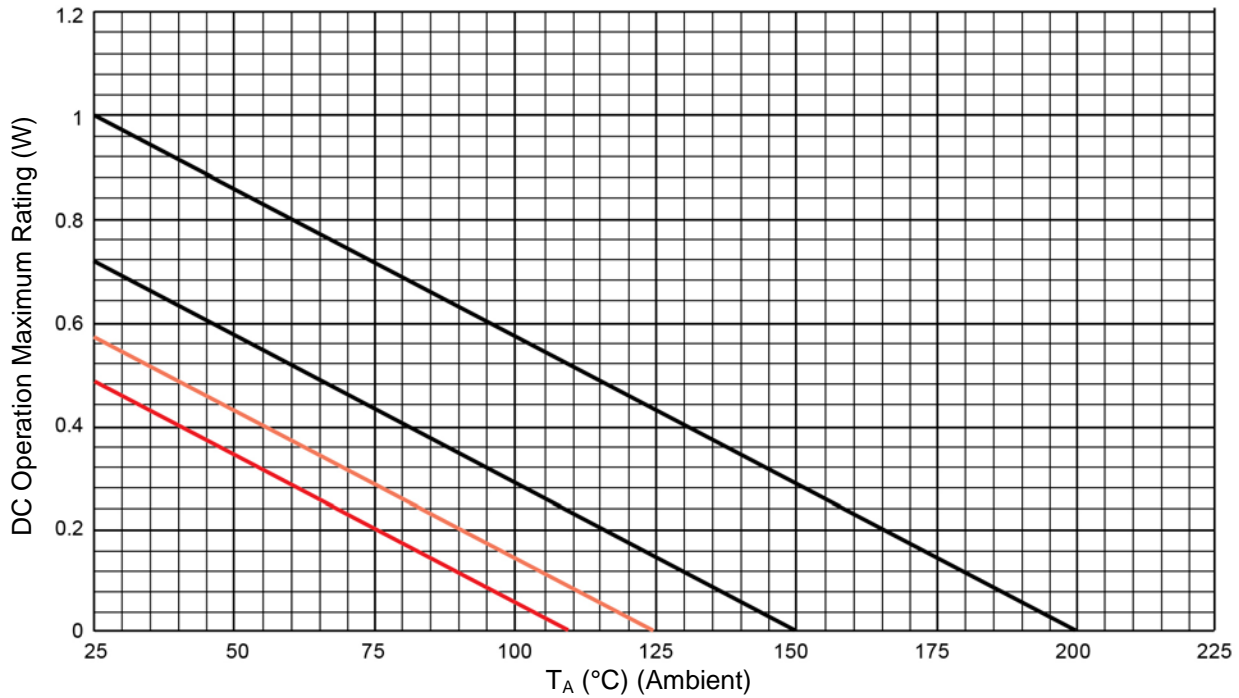
 $V_{CE} = 16.67\text{ V}, I_C = 300\text{ mA}$ 2N3500L, 2N3501L

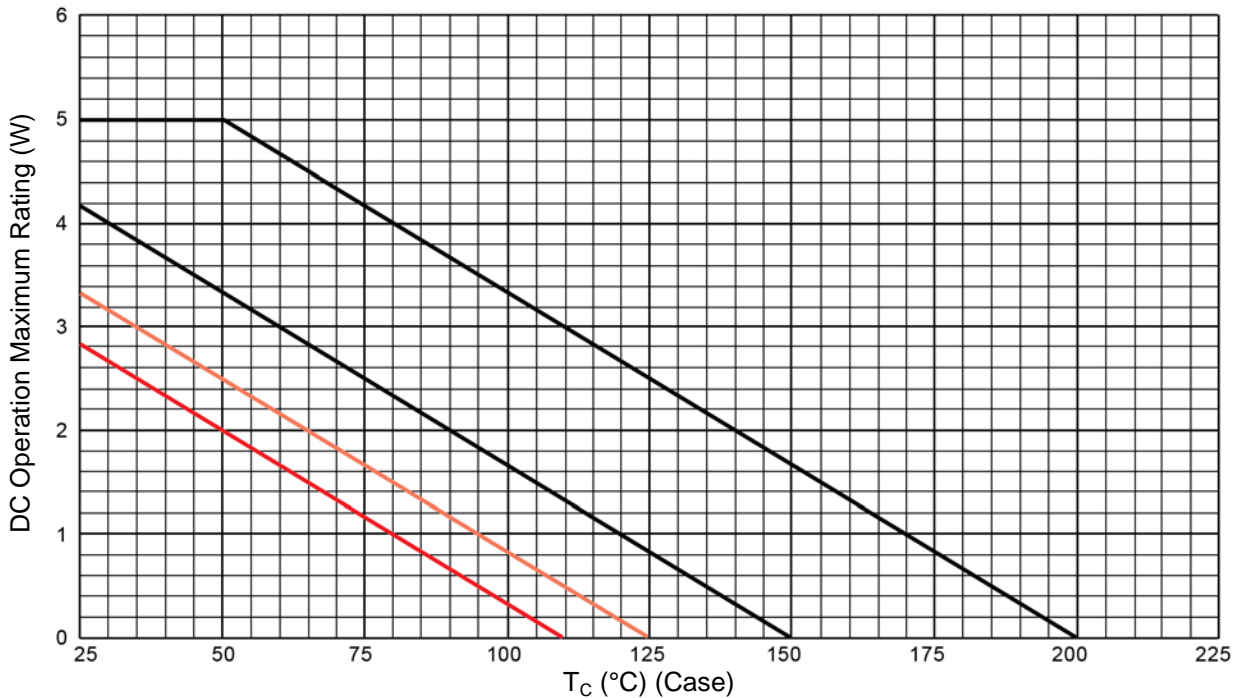
Test 2
 $V_{CE} = 50\text{ V}, I_C = 100\text{ mA}$ All Types

Test 3
 $V_{CE} = 80\text{ V}, I_C = 40\text{ mA}$ All Types

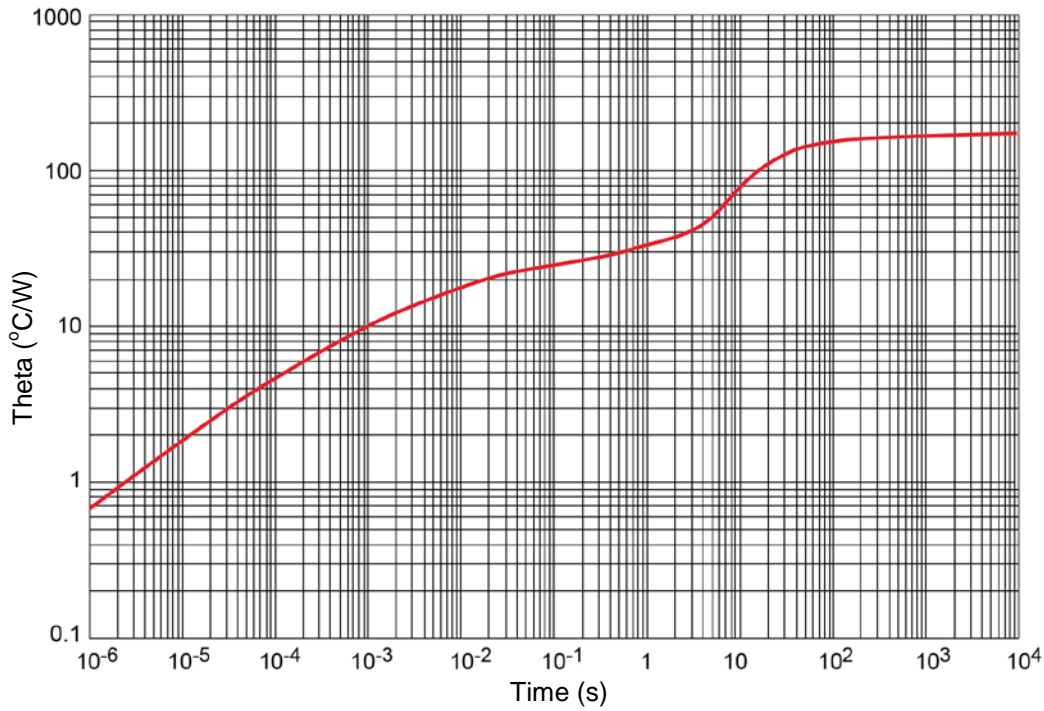
Clamped Switching
 $T_A = +25\text{ }^\circ\text{C}$
Test 1
 $I_B = 85\text{ mA}, I_C = 500\text{ mA}$ 2N3498L, 2N3499L

 $I_B = 50\text{ mA}, I_C = 300\text{ mA}$ 2N3500L, 2N3501L

Maximum Safe Operating Area

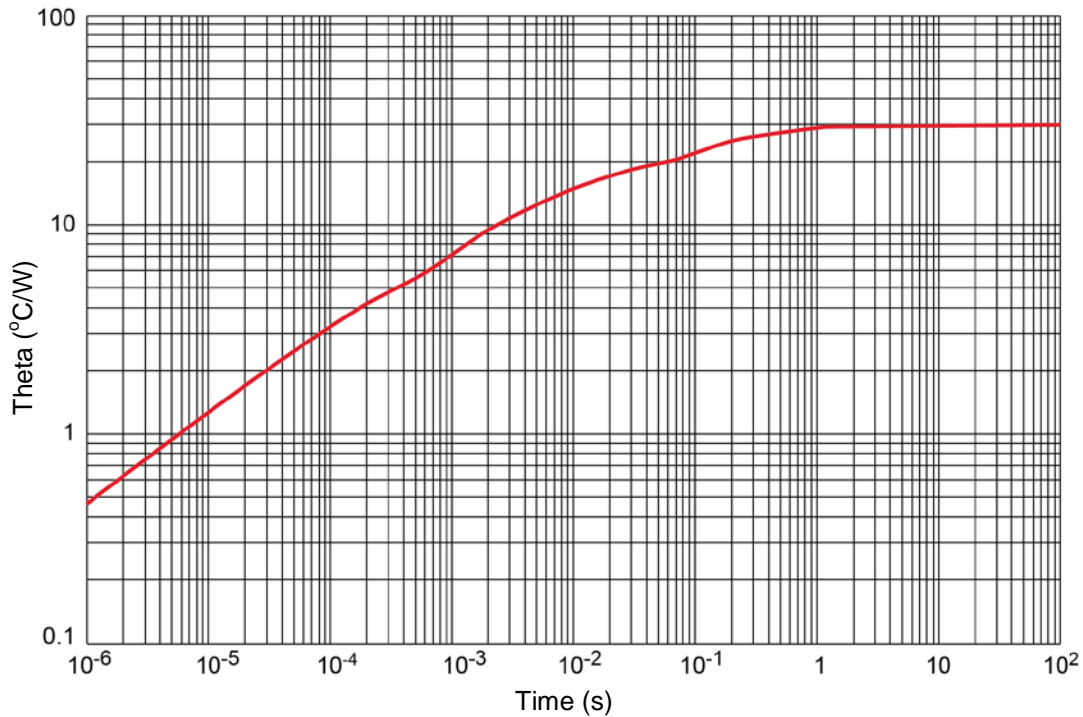
GRAPHS

FIGURE 1

 Derating for all devices ($R_{\theta JA}$)

FIGURE 2

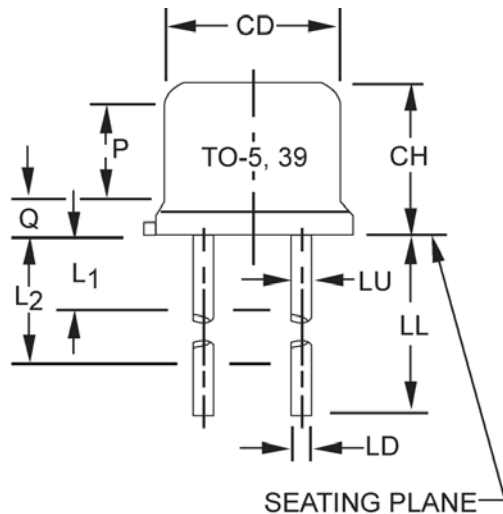
 Derating for all devices ($R_{\theta JC}$)

GRAPHS

FIGURE 3

Thermal impedance graph ($R_{\theta JA}$)


FIGURE 4

Thermal impedance graph ($R_{\theta JC}$)

PACKAGE DIMENSIONS


Symbol	Dimensions				Note
	Inch		Millimeters		
	Min	Max	Min	Max	
CD	0.305	0.335	7.75	8.51	
CH	0.240	0.260	6.10	6.60	
HD	0.335	0.370	8.51	9.40	
LC	0.200 TP		5.08 TP		6
LD	0.016	0.021	0.41	0.53	7
LL	See notes 7, 12 and 13				
LU	0.016	0.019	0.41	0.48	7, 13
L1		0.050		1.27	13
L2	0.250		6.35		13
P	0.100		2.54		5
Q		0.050		1.27	4
TL	0.029	0.045	0.74	1.14	3
TW	0.028	0.034	0.71	0.86	10, 11
r		0.010		0.25	11
α	45° TP		45° TP		6

NOTES:

- Dimensions are in inches.
- Millimeters are given for general information only.
- Symbol TL is measured from HD maximum.
- Details of outline in this zone are optional.
- Symbol CD shall not vary more than .010 (0.25 mm) in zone P. This zone is controlled for automatic handling.
- Leads at gauge plane .054 inch (1.37 mm) +.001 inch (0.03 mm) -.000 inch (0.00 mm) below seating plane shall be within .007 inch (0.18 mm) radius of true position (TP) relative to tab. Device may be measured by direct methods or by gauge.
- Symbol LD applies between L1 and L2. Dimension LD applies between L2 and LL minimum. Lead diameter shall not exceed .042 inch (1.07 mm) within L1 and beyond LL minimum.
- Lead designation, shall be as follows: 1 - emitter, 2 - base, 3 - collector.
- Lead number three is electrically connected to case.
- Beyond r maximum, TW shall be held for a minimum length of .011 inch (0.28 mm).
- Symbol r applied to both inside corners of tab.
- For transistor types 2N3498, 2N3499, 2N3500, and 2N3501, LL = .50 inch (12.7 mm) minimum and .750 inch (19.1 mm) maximum. For transistor types 2N3498L, 2N3499L, 2N3500L, and 2N3501L, LL = 1.50 inches (38.1 mm) minimum and 1.750 inches (44.5 mm) maximum.
- All three leads.
- In accordance with ASME Y14.5M, diameters are equivalent to Φ x symbology.

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Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: ocean@oceanchips.ru

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А